**Duration: 3hrs** 

[Max Marks:80]

N.B	.:	<ol> <li>Question No 1 is Compulsory.</li> <li>Attempt any three questions out of the remaining five.</li> <li>All questions carry equal marks.</li> <li>Assume suitable data, if required and state it clearly.</li> </ol>	S CO
			30
1		Attempt any FOUR	[20]
	a	Why is the JFET called as a square law device?	
	b	Write a short note on single electron transistors (SET). Include suitable neat	9
		sketches wherever necessary.	
	c	With neat sketch describe operation of the inductor (L) filter with appropriate waveforms.	
	d	Explain the concept of DC load line & Q – Point in bipolar junction transistor (BJT).	180
	e	Describe combinational clipper circuits with neat diagram & transfer	
		characteristics.	
2	a	Describe the working or operation of a bridge type full wave rectifier with a neat	[10]
		sketch. Draw the output voltage waveforms & mention the expression for DC or	
		average output voltage (Vdc)	
	b	With a neat sketch, explain the Zener diode as a voltage regulator. Describe its operation for both, varying load resistance with a constant DC supply voltage &	[10]
		a varying DC supply voltage with a constant load resistance.	F1.01
3	a	Explain how a PN junction is formed with a neat diagram.	[10]
	b	Explain with the help of neat diagram construction, working & VI characteristics	[10]
		of n channel depletion MOSFET.	
4	a	Draw a circuit diagram of common source (CS) E-MOSFET amplifier, derive	[10]
		equation of voltage gain (Av), input resistance (Ri) & output resistance (Ro)?	
	b	For small signal amplifier in common emitter (CE) BJT configuration using	[10]
57		voltage divider biasing perform small signal (AC) analysis using the hybrid – $\pi$ model.	

## Paper / Subject Code: 51122 / Electronic Devices

- 5 a With a neat sketch, write a short note on solar cell describing its structure or construction, working & V-I characteristics. Mention few real-life applications of solar cells
  - b Draw circuit diagram and explain the operation of different biasing circuits used [10] for D-MOSFET.
- 6 a Explain construction and working principle of Memristor. [10]
  - b Draw all the different biasing circuits of BJT. Derive the expression of stability [10] factor (SI) for the voltage divider biasing circuit.

38480 Page 2 of 2